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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







# SCS206AJHR

## **Automotive Grade SiC Schottky Barrier Diode**

Datasheet

$V_R$	650V
I <sub>F</sub>	6A
$Q_{C}$	9nC

# ●Outline LPT(L) <TO-263AB> (2) (3) (4)

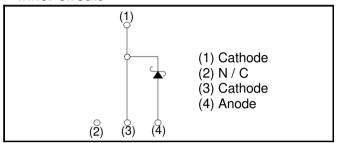
#### Features

- 1) AEC-Q101 qualified
- 2) Low forward voltage
- 3) Negligible recovery time/current
- 4) Temperature independent switching behavior

## Applications

- On Board Charger
- DC/DC Converter
- · Wireless Charger
- EV Charger

#### •Inner circuit



Packaging specifications

	<del>5                                    </del>	
	Packaging	Embossed tape
	Reel size (mm)	330
Tuno	Tape width (mm)	24
Type	Basic ordering unit (pcs)	1 000
	Packing code	TLL
	Marking	SCS206AJ

## ● Absolute maximum ratings (T<sub>i</sub> = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	$V_{RM}$	650	V
Reverse voltage (De	C)	$V_R$	650	V
Continuous forward	current (T <sub>c</sub> = 136°C)	I <sub>F</sub>	6	А
Surge non-	PW=10ms sinusoidal, T <sub>j</sub> =25°C		23	А
repetitive forward	PW=10ms sinusoidal, T <sub>j</sub> =150°C	I <sub>FSM</sub>	18	А
current	PW=10μs square, T <sub>j</sub> =25°C		90	А
Repetitive peak forward current		I <sub>FRM</sub>	26 *1	А
PW=10ms, T <sub>j</sub> =25°C		۲ ،2	2.6	A <sup>2</sup> s
i <sup>2</sup> t value PW=10ms, T <sub>j</sub> =150°C		$\int i^2 dt$	1.6	A <sup>2</sup> s
Total power dissipation		P <sub>D</sub>	48 *2	W
Junction temperature		T <sub>j</sub>	175	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +175	°C

<sup>\*1</sup> T<sub>c</sub>=100°C, T<sub>i</sub>=150°C, Duty cycle=10% \*2 T<sub>c</sub>=25°C

# ●Electrical characteristics (T<sub>j</sub> = 25°C)

Parameter Sy	Symbol	Conditions	Values			Lloit
	Symbol		Min.	Тур.	Max.	Unit
DC blocking voltage	$V_{DC}$	I <sub>R</sub> =1.2mA	650	-	-	V
	V <sub>F</sub>	I <sub>F</sub> =6A,T <sub>j</sub> =25°C	-	1.35	1.55	V
Forward voltage		I <sub>F</sub> =6A,T <sub>j</sub> =150°C	-	1.55	-	V
		I <sub>F</sub> =6A,T <sub>j</sub> =175°C	-	1.63	-	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =600V,T <sub>j</sub> =25°C	-	1.2	120	μΑ
		V <sub>R</sub> =600V,T <sub>j</sub> =150°C	-	18	-	μΑ
		V <sub>R</sub> =600V,T <sub>j</sub> =175°C	-	42	-	μΑ
Total capacitance	С	V <sub>R</sub> =1V,f=1MHz	-	220	-	pF
		V <sub>R</sub> =600V,f=1MHz	-	22	-	pF
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	9	-	nC
Switching time	t <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	1	12	-	ns

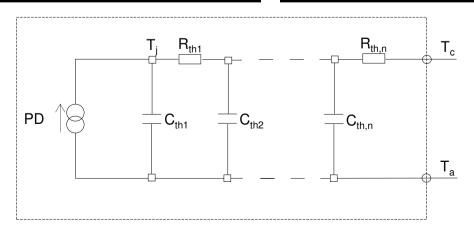
#### Thermal characteristics

Parameter	Symbol	Conditions	Values			Lloit
			Min.	Тур.	Max.	Unit
Thermal resistance	$R_{th(j-c)}$	-	-	2.3	3.1	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R <sub>th1</sub>	2.28E-01	
R <sub>th2</sub>	1.53E+00	K/W
R <sub>th3</sub>	5.41E-01	

Symbol	Value	Unit
C <sub>th1</sub>	1.05E-03	
C <sub>th2</sub>	4.56E-04	Ws/K
$C_{th3}$	1.28E-02	



#### • Electrical characteristic curves

Fig.1 V<sub>F</sub> - I<sub>F</sub> Characteristics

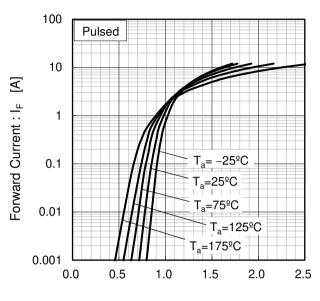
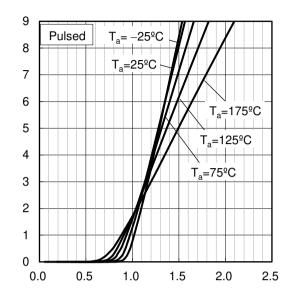


Fig.2 V<sub>F</sub> - I<sub>F</sub> Characteristics



Forward Voltage :  $V_F$  [V] Forward Voltage :  $V_F$  [V]

Forward Current : IF [A]

Fig.3 V<sub>R</sub> - I<sub>R</sub> Characteristics

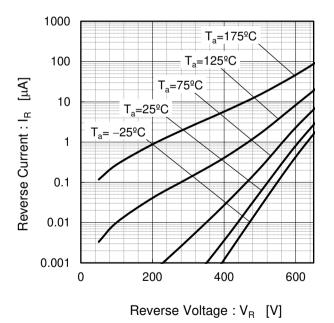
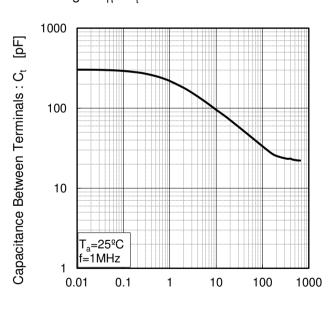


Fig.4 V<sub>R</sub> - C<sub>t</sub> Characteristics



Reverse Voltage : V<sub>R</sub> [V]

175

150

#### Electrical characteristic curves

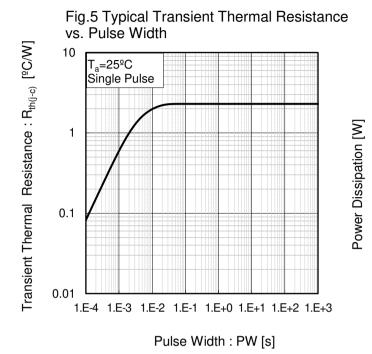


Fig.6 Power Dissipation

50
45
40
35
30
25
20
15
10

5

25

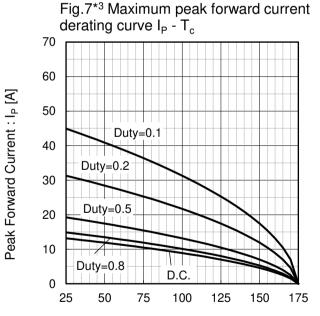
50

75

Case Temperature : T<sub>c</sub> [ºC]

125

100



Case Temperature : T<sub>c</sub> [°C] \*3 Based on max Vf, max R<sub>th(j-c)</sub> Valid for switching of above 10kHz, excluding D.C. curve.

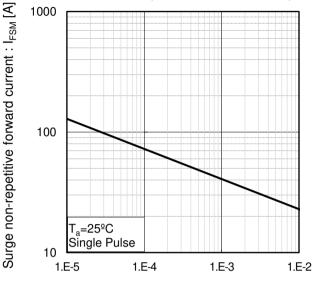
Fig.8\*4 Typical peak forward current derating curve I<sub>P</sub> - T<sub>c</sub> (Not guaranteed) 60 Dutv=0.1 50 Duty=0.2 40 30 Duty=0.5 20 10 Duty=0.8 D.C. 0 25 50 75 100 125 150 175

Case Temperature :  $T_c$  [ ${}^{\circ}$ C] \*4 Based on typ Vf, typ  $R_{th(j-c)}$  Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Peak Forward Current : I<sub>P</sub> [A]

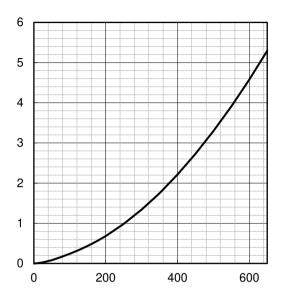
#### •Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

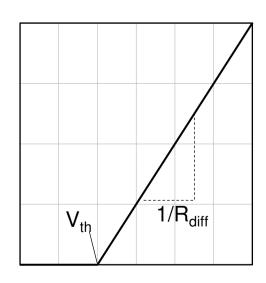
Fig.10 Typical capacitance store energy



Reverse Voltage: V<sub>R</sub> [V]

### Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V<sub>F</sub>

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} & V_{th} \left( \ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ & R_{diff} \left( \ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
$a_0$	9.35E-01	V
a <sub>1</sub>	-1.12E-03	V/°C
b <sub>0</sub>	6.63E-02	Ω
b <sub>1</sub>	1.70E-04	Ω/°C
b <sub>2</sub>	1.80E-06	$\Omega$ /°C <sup>2</sup>

 $T_i \text{ in } {}^{\circ}\text{C}$ ; -55  ${}^{\circ}\text{C}$  <  $T_i < {}^{\circ}\text{C}$  ;  $I_F < 12 \text{ A}$ 

Forward Current: IF

Capacitance stored energy :  $\mathsf{E}_\mathsf{C}[\mu J]$ 

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# SCS206AJHR - Web Page

**Distribution Inventory** 

Part Number	SCS206AJHR
Package	TO-263AB (LPTL)
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes